Am139/239/339 · Am139A/239A/339A

Low Offset Voltage Quad Comparators

Distinctive Characteristics

- Four high precision comparators
- Reduced VOS drift over temperature
- Eliminates need for dual supplies
- Allows sensing near ground
- Wide single supply voltage range or dual supplies 2.0 V_{DC} to 36 V_{DC}
 - $\pm 1.0 \, \text{V}_{DC}$ to $\pm 18 \, \text{V}_{DC}$
- Very low supply current drain (0.8mA)—independent of supply voltage (1.0mW/comparator) makes these comparators suitable for battery operation.

- Low input bias current 35 nA
- Low input offset current 3.0 nA and offset voltage – 2.0 mV
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Low output saturation voltage 1.0mV at 5.0μA 60mV at 1.0mA
- Output voltage compatible with TTL, DTL, ECL MOS and CMOS logic systems

FUNCTIONAL DESCRIPTION

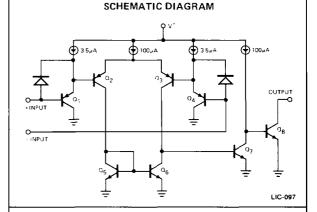
The Am139, Am239, Am339, Am339A, Am239A and Am339A quad comparators are functionally, electrically and pin-for-pin equivalent to the National LM139, LM239, LM339, LM339A, EM239A and LM339A. This series of precision comparators consists of four independent voltage comparators which were specifically designed to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators have a unique characteristic

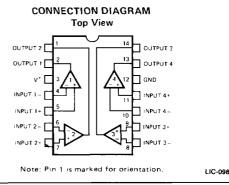
in that the input common-mode voltage range includes ground even though operated from a single power supply voltage.

Application areas include limit comparators, simple analog to digital converters; pulse, squarewave and time delay generators; wide range VCO; MOS clock timers; multivibrators and high voltage digital logic gates. The Am139/A series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the Am139/A will directly interface with MOS logic — where the lower power drain of the Am139/A is a distinct advantage over standard comparators.

ORDERING INFORMATION

Part Number	Package Type	Temperature Range	Order Number			
Am339	DIP	0°C to 70°C	LM339D			
	Molded DIP	0°C to 70°C	LM339N			
	Dice	0°C to 70°C	LD339			
Am239	DIP	−25°C to +85°C	LM239D			
Am139	DIP	–55° C to +125° C	LM139D			
	Flat Pack	-55°C to +125°C	LM139F			
	Dice	–55°C to +125°C	LD139			
Am339A	DIP	0°C to 70°C	LM339AD			
	Molded DIP	0° C to 70° C	LM339AN			
	Dice	0°C to 70°C	LD339A			
Am239A	DIP	-25° C to +85° C	LM239AD			
Am139A	DIP	-55°C to +125°C	LM139AD			
	Flat Pack	–55°C to +125°C	LM139AF			
	Dice	-55°C to +125°C	LD139A			





Am139/239/339 • Am139A/239A/339A

ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS (Above which the useful life may be impaired)

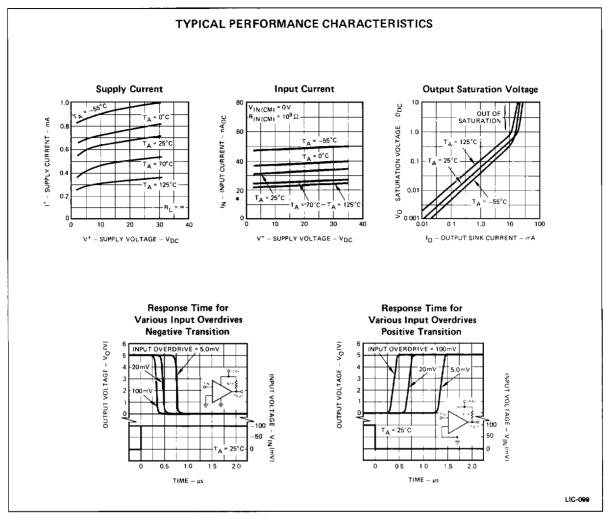
Supply Voltage, V+	$36\mathrm{V_{DC}}$ or $\pm18\mathrm{V_{DC}}$						
Differential Input Voltage	36 V _{DC}						
Input Voltage	-0.3 V _{DC} to +36 V _{DC}						
Power Dissipation (Note 1)	West 000						
Ceramic Dip	900 mW						
	900 mW 570 mW 800 mW						

Output Short Circuit to GND (Note 2)	Continuous
Input Current (Vin -0.3 VDC) (Note 3)	50 mA
Operating Temperature Range	
Am 339/A	0°C to +70°C
Am 239/A	-25°C to +85°C
Am139/A	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10 seconds)	300°C

ELECTRICAL CHAF V ⁺ = +5.0V _{DC}) (Note 4		TERISTICS			Am139			Am239A Am339A			Am139A			
arameters	Test Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Input Offset Voltage	T _A = +25°C (Note 9)		-2.0	±5 0		±2.0	±5.0		+1.0	=2.0		: 1.0	±2.0	m∨DC
Input Bias Current (Note 5)	$I_{[N(+)]}$ or $I_{[N(-)]}$ with Output in Linear Range, $T_{\Delta} = +25^{\circ}C$		25	250		25	100		25	250		25	100	nADC
Input Offset Current	IIN(+) - IIN(-), TA = +25°C		:5.0	-50		:3.0	: 25		٠5.0	•50		:3.0	: 25	nADC
Input Common-Mode Voltage Range (Note 6)	T _A = +25°C	0		V ⁺ -1.5	0		V ⁺ ~1.5	0		V ⁺ -1.5	0		V ⁺ -1.5	VDC
Supply Current	R _L = \(\omega\) on all Comparators T _A = +25° C		0.8	2.0		0.8	2.0		0.8	2.0		0.8	2.0	mADC
Voltage Gain	$R_L \ge 15 k\Omega$, $T_A = +25^{\circ}C$, $V^{+} = 15 V_{DC}$ (To Support Large V_0 Swing)		200		-	200		50	200		50	200		V/mV
Large Signal Response Time	V_{IN} = TTL Logic Swing, V_{REF} = +1.4 V_{DC} , V_{R_L} = 5.0 V_{DC} , R_L = 5.1 $k\Omega$ and T_A = +25°C		300			300			300	!		300		ns
Response Time (Note 7)	$V_{R_L} = 5.0 V_{DC}$ and $R_L = 5.1 k\Omega$ $T_A = +25^{\circ}C$		1.3			1.3			1.3			1.3		μs
Output Sink Current	$V_{ N -1} \ge +1.0 V_{DC}, V_{ N +} = 0,$ and $V_0 \le +1.5 V_{DC}, T_A = +25^{\circ}C$	6.0	16		6.0	16		60	16	_	6.0	16		mADC
Saturation Voltage	$V_{\{N\{-\}\}} \ge +1.0 \text{ V}_{DC}, V_{\{N\{+\}\}} = 0,$ and $I_{sink} \le 4.0 \text{ mA}, T_A = +25^{\circ} \text{ C}$		250	400		250	400		250	400		250	400	m∨DC
Output Leakage Current	$V_{ N +} = +1.0 V_{DC}, V_{ N -} = 0$ and $V_0 = 5.0 V_{DC}, T_A = +25 C$		0.1			0.1			0.1			0.1		nADC
Input Offset Voltage	(Note 9)			9.0		T	9.0			4.0			4.0	m∨pc
Input Offset Current	1IN(+) = IIN(-)			•150		ļ	:100			150		<u> </u>	100	nADC
Input Bias Current	IN(+) or IN(_) with Output in Linear Range		 	400			300			400			300	nADC
Input Common-Mode Voltage Range		О		V ⁺ -2.0	0		v ⁺ −2.0	0		V ⁺ -2.0	0		V*-2.0	V _{DC}
Saturation Voltage	$V_{IN(+)} \ge +1.0 \text{ V}_{DC}$, $V_{IN(+)} = 0$ and $I_{sink} \le 4.0 \text{ mA}$			700			700			700			700	mV _{DC}
Output Leakage Current	$V_{ N\{+\}} \neq +1.0 \text{ VDC}, V_{ N\{-\}} = 0$ and $V_0 = 30 \text{ VDC}$			1.0			1.0			1.0			1.0	"ADC
Differential Input Voltage (Note 8)	Keep all $V_{1N^*s} \ge 0 \ V_{DC}$ (or V^- if used)			36			36			v+			v+	V _{DC}

- Note 1: For high temperature operation, the Am339/A must be derated based on a +125°C maximum junction temperature and a thermal resistance of +175°C/W which applies for the device soldered in a printed circuit board, operating in a still air ambient. The Am239/A and Am139/A must be derated based on a +150°C maximum junction temperature. The low bias dissipation and the ON-OFF characteristic of the outputs keeps the chip dissipation very small (Pd ≤ 100 mW), provided the output transistors are allowed to saturate.
 - 2: Short circuits from the output to V⁺ can cause excessive heating and eventual destruction. The maximum output current is approximately 20 mA independent of the magnitude of V⁺.
 - 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V⁺ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is, not destructive and normal outputs states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 V_{DC}.
 - 4: These specifications apply for V⁺ = +5.0 V_{DC} and -55°C \leq T_A \leq +125°C, unless otherwise stated. With the Am239/A all temperature specifications are limited to -25°C \leq T_A \leq +85°C and the Am339/A temperature specifications are limited to 0°C \leq T_A \leq +70°C.
 - 5: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.
 - 6: The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V⁺-1.5 V, but either or both inputs can go to +30 V_{DC} without damage.
 7: The response time specified is for a 100mV input step with 5.0mV overdrive, 300ns can be achieved with larger overdrive signals, see typical
 - performance characteristics section.

 8: If the voltage applied to any input exceeds V*, all four comparator outputs will go to the high voltage level. The low input voltage state must not
 - 8: If the voltage applied to any input exceeds V*, all four comparator outputs will go to the high voltage level. The low input voltage state must not be less than -0.3 VDC (or 0.3 VDC below the magnitude of the negative power supply, if used).
 - 9: At output switch point, $V_O \cong 1.4 V_{DC}$, $R_S = 0\Omega$ with V⁺ from 5.0 V_{DC} ; and over the full input common mode range (0 V_{DC} to V⁺ -1.5 V_{DC}).



APPLICATION HINTS

The Am139/A is a high gain, wide bandwidth device; which like most comparators, can easily oscillate if the output lead is inadvertently allowed to capacitively couple to the inputs via stray capacitance. The oscillation shows up only during the output voltage transition intervals as the comparator changes states. Power supply bypassing is not required to solve this problem. Standard PC board-layout is helpful as it reduces stray input-output coupling. Lowering the input resistors to $<10k\Omega$ reduces the feedback signal levels and finally, adding even a small amount (1 to 10 mV) of positive feedback (hysteresis) causes such a rapid transition that oscillations due to stray feedback are not possible. Simply socketing the I/C card attaching resistors to the pins will cause input-output oscillations during the small transition intervals unless hysteresis is used. If the input signal is a pulse waveform, with relatively fast rise and fall times, hysteresis is not required.

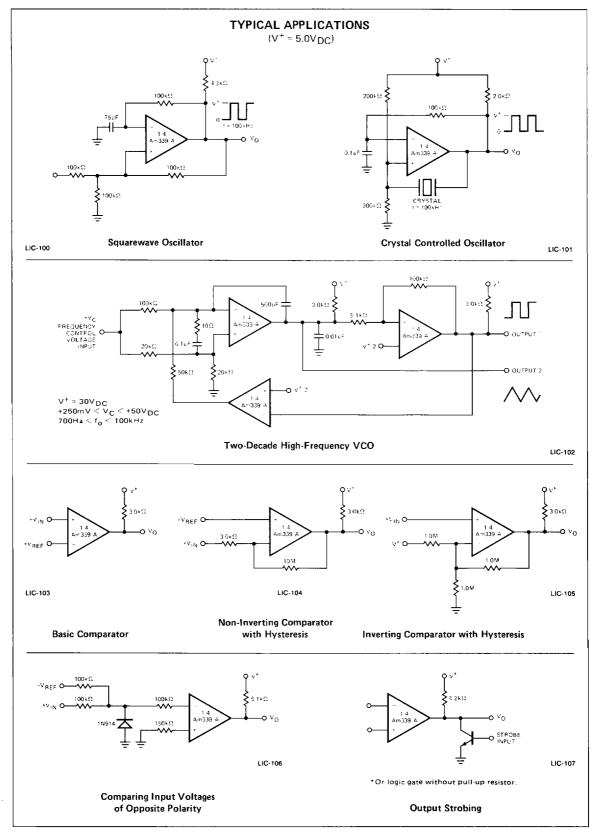
All pins of any unused comparators should be grounded.

The bias network of the Am139/A establishes a drain current which is independent of the magnitude of the power supply voltage over the range of from $2V_{DC}$ to $30~V_{DC}$.

It is not normally necessary to use a bypass capacitor across the power supply line.

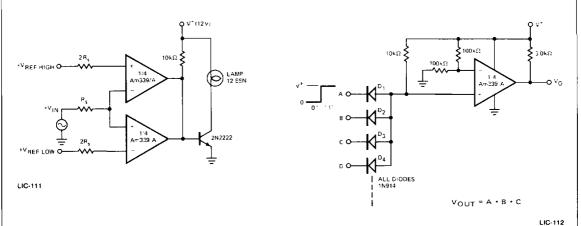
The differential input voltage may be larger than V^+ without damaging the device. Protection should be provided to prevent the input voltages from going negative more than $-0.3V_{DC}$ (at 25°C). An input clamp diode and input resistor can be used as shown in the applications section.

The output of the Am139/A is the uncommitted collector of a grounded-emitter NPN output transistor. Several collectors can be tied together to provide an output OR'ing function. An output "pull-up" resistor can be connected to any available power supply voltage within the permitted supply voltage range and there is no restriction on this voltage due to the magnitude of the voltage which is applied to the V+ terminal of the Am139/A package. The output can also be used as a simple SPST switch to ground (when a "pull-up" resistor is not used). The amount of current which the output device can sink is limited by the drive available (which is independent of V^+) and the β of this device. When the maximum current limit is reached (approximately 16 mA), the output transistor will come out of saturation and the output voltage will rise very rapidly. The output saturation voltage is limited by the approximately $60\Omega\ r_{\text{sat}}$ of the output transistor. The low offset voltage of the output transistor (1 mV) allows the output to clamp very nearly to ground level for small load currents.



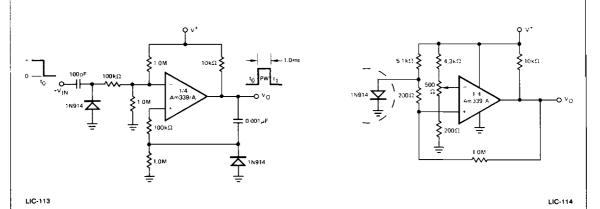
TYPICAL APPLICATIONS (Cont.) (V⁺ = 5.0V_{DC}) V 14 DM54XX LIC-108 LIC-109 LIC-110 Driving TTL Driving CMOS

 $(V^{+} = 15V_{DC})$



Limit Comparator

Large Fan-In AND Gate



One-Shot Multivibrator

Remote Temperature Sensing

TYPICAL APPLICATIONS (Cont.) $(V^{+} = 15V_{DC})$ **₹**10M ₹560kΩ **₹**10M 100kΩ 1014 62kΩ **≷ \$** 240kΩ LIC-115 One-Shot Multivibrator with Input Lock Out **Q** +15 v -**√√**-100kΩ 51+11 80 n F 100kΩ *For large ratios of R₁/R₂, D₁ can be omitted. LIC-117 LIC-116 **Pulse Generator** Bi-Stable Multivibrator